## NSN 5961-00-118-8441

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View Online at https://aerobasegroup.com/nsn/5961-00-118-8441 **Inclosure Material:** Metal **Overall Length:** 0.375 inches **Overall Diameter:** 0.875 inches **Mounting Facility Quantity:** 2 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 400.0 breakdown voltage, collector-to-emitter, with specified circuit between base and emitter and 400.0 collector to base voltage, dc and 5.0 emitter to base voltage, instantaneous **Current Rating Per Characteristic:** Between 2.00 amperes source cutoff current and 10.00 amperes source cutoff current **Power Rating Per Characteristic:** 125.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0